Document No.: FT_000628 Clearance No.: FTDI# 265



Future Technology Devices International Ltd. FT200XD (USB I2C SLAVE IC)



The FT200XD is a USB to I²C interface • with the following advanced features:

- Single chip USB to I²C interface.
- Up to 3.4MHz, high speed mode, I²C supported
- Entire USB protocol handled on the chip. No USB specific firmware programming required.
- Fully integrated 2048 byte multi-timeprogrammable (MTP) memory storing device descriptors and CBUS I/O configuration.
- Fully integrated clock generation with no external crystal required plus optional clock output selection enabling a glue-less interface to external MCU or FPGA.
- 512 byte receive buffer and 512 byte transmit buffer utilising buffer smoothing technology to allow for high data throughput.
- FTDI's royalty-free Virtual Com Port (VCP) and Direct (D2XX) drivers eliminate the requirement for USB driver development in most cases.
- Unique USB FTDIChip-ID™ feature.
- Configurable CBUS I/O pin.
- Transmit and receive LED drive signals.
- USB Battery Charger Detection. Allows for USB peripheral devices to detect the presence of a higher power source to enable improved charging.
- Device supplied pre-programmed with unique USB serial number.

- USB Power Configurations; supports buspowered, self-powered and bus-powered with power switching.
- Integrated +3.3V level converter for USB I/O.
- True 3.3VCMOS drive output and TTL input;
 Operates down to 1V8 with external pull-ups.
 Tolerant of 5V input.
- Configurable I/O pin output drive strength; 4 mA(min) and 16 mA(max).
- Integrated power-on-reset circuit.
- Fully integrated AVCC supply filtering no external filtering required.
- + 5V Single Supply Operation.
- Internal 3V3/1V8 LDO regulators
- Low operating and USB suspend current; 8mA (active-typ) and 125uA (suspend-typ).
- UHCI/OHCI/EHCI host controller compatible.
- USB 2.0 Full Speed compatible.
- Extended operating temperature range; -40°C to +85°C.
- Available in compact Pb-free 10 Pin DFN package (3mmx3mm) (RoHS compliant).

Neither the whole nor any part of the information contained in, or the product described in this manual, may be adapted or reproduced in any material or electronic form without the prior written consent of the copyright holder. This product and its documentation are supplied on an as-is basis and no warranty as to their suitability for any particular purpose is either made or implied. Future Technology Devices International Ltd will not accept any claim for damages howsoever arising as a result of use or failure of this product. Your statutory rights are not affected. This product or any variant of it is not intended for use in any medical appliance, device or system in which the failure of the product might reasonably be expected to result in personal injury. This document provides preliminary information that may be subject to change without notice. No freedom to use patents or other intellectual property rights is implied by the publication of this document. Future Technology Devices International Ltd, Unit 1, 2 Seaward Place, Centurion Business Park, Glasgow G41 1HH United Kingdom. Scotland Registered Company Number: SC136640

Version 1.3

Document No.: FT_000628 Clearance No.: FTDI# 265

1 Typical Applications

- Upgrading Legacy Peripherals to USB
- Utilising USB to add system modularity
- Incorporate USB interface to enable PC transfers for development system communication
- Motherboard and system monitoring through USB
- USB dongle implementations for Software/ Hardware Encryption and Wireless Modules
- Interfacing MCU/PLD/FPGA based designs to add USB connectivity
- USB Instrumentation
- USB Industrial Control
- USB Digital Camera Interface
- Capable of detecting dedicated USB charger ports for charging batteries with high current

1.1 Driver Support

Royalty free VIRTUAL COM PORT (VCP) DRIVERS for...

- Windows 8 32-,64-bit
- Windows 7 32-,64-bit
- Windows Vista and Vista 64-bit
- Windows XP and XP 64-bit
- Windows Embedded Operating Systems
- Server 2003, XP and Server 2008
- Windows CE 4.2, 5.0 and 6.0
- Mac OS-X
- Linux 3.2 and greater
- Android OS

Royalty free D2XX *Direct* Drivers (USB Drivers + DLL S/W Interface)

- Windows 8 32-,64-bit
- Windows 7 32-,64-bit
- Windows Vista and Vista 64-bit
- Windows XP and XP 64-bit
- Windows Embedded Operating Systems
- Server 2003, XP and Server 2008
- Windows CE 4.2, 5.0 and 6.0
- Mac OS-X
- Linux 2.6 and greater
- Android OS

The drivers listed above are all available to download for free from FTDI website (www.ftdichip.com). Various 3rd party drivers are also available for other operating systems - see FTDI website(www.ftdichip.com) for details.

For driver installation, please refer to http://www.ftdichip.com/Documents/InstallGuides.htm

1.2 Part Numbers

Part Number	Package		
FT200XD-x	10 Pin DFN		

Table 1.1 Ordering part numbers

Note: Packing codes for -x is:

- R: Taped and Reel, 5,000pcs per reel

- T: Tray packing, 490pcs per tray

For example: FT200XD-R is 5,000pcs taped and reel packing



Version 1.3

Document No.: FT_000628 Clearance No.: FTDI# 265

1.3 USB Compliant

The FT200XD is fully compliant with the USB 2.0 specification and has been given the USB-IF Test-ID (TID) 40001459 (Rev D).



Version 1.3

Document No.: FT_000628 Clearance No.: FTDI# 265

2 FT200XD Block Diagram

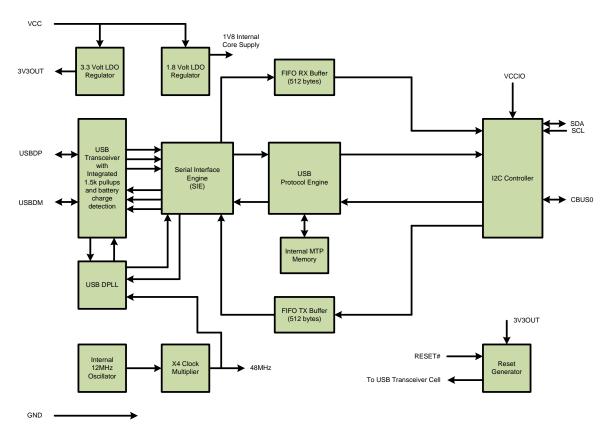


Figure 2.1FT200XD Block Diagram

For a description of each function please refer to Section 4.



Table of Contents

1	Typical Applications	2
1.1	Driver Support	2
1.2	Part Numbers	2
1.3	USB Compliant	3
2	FT200XD Block Diagram	4
3	Device Pin Out and Signal Description	7
3.1	10-LD DFN Package	
3.1	1 DFN Package Pin Out Description	7
3.2	CBUS Signal Options	9
4	Function Description	10
4.1	Key Features	10
4.2	Functional Block Descriptions	10
5	I ² C Interface Description	12
6	Devices Characteristics and Ratings	13
6.1	Absolute Maximum Ratings	13
6.2	ESD and Latch-up Specifications	13
6.3	DC Characteristics	14
6.4	MTP Memory Reliability Characteristics	18
6.5	Internal Clock Characteristics	18
7	USB Power Configurations	19
7.1	USB Bus Powered Configuration	19
7.2	Self Powered Configuration	20
7.3	USB Bus Powered with Power Switching Configuration	21
8	Application Examples	22
8.1	USB to I ² C Converter	22
8.2	USB Battery Charging Detection	23
9	USB and I ² C Interfacing	25
9.1	Host Interface (USB)	25
9.1	1 VCP and D2xx Interfaces	25
9.1		
9.2		
9.2		
9.2		
9.3		
10	Internal MTP Memory Configuration	31



Version 1.3 Document No.: FT_000628 Clearance No.: FTDI# 265

10.1	Default Values	31
10.2	Methods of Programming the MTP Memory	32
10.2.1	Programming the MTP memory over USB	32
10.2.2	Programming the MTP memory over I ² C	32
10.3	Memory Map	33
10.4	Hardware Requirements	34
10.5	Protocol	34
10.5.1	Address MTP memory (0x10)	34
10.5.2	Write MTP memory (0x12)	34
10.5.3	Read MTP memory (0x14)	34
10.5.4	Examples of Writing and Reading	34
11 Pa	ckage Parameters	36
11.1	DFN-10 Package Mechanical Dimensions	36
11.2	Package Markings	37
11.3	Solder Reflow Profile	38
12 Co	ntact Information	39
Appen	dix A – References	40
Appen	dix B - List of Figures and Tables	41
Append	dix C - Revision History	42

Document No.: FT_000628 Clearance No.: FTDI# 265

3 Device Pin Out and Signal Description

3.1 10-LD DFN Package

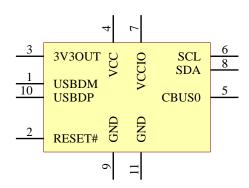


Figure 3.1 DFN Schematic Symbol

3.1.1 DFN Package Pin Out Description

Note: # denotes an active low signal.

Pin No.	Name	Туре	Description			
4	** VCC	POWER Input	5 V (or 3V3) supply to IC			
7	VCCIO	POWER Input	1V8 - 3V3 supply for the IO cells			
3	** 3V3OUT	POWER Output	3V3 output at 50mA. May be used to power VCCIO. When VCC is 3V3; pin 3 is an input pin and should be connected to pin 4.			
9	GND	POWER Input	0V Ground input.			

Table 3.1 Power and Ground

^{**} If VCC is 3V3 then 3V3OUT must also be driven with 3V3 input

Pin No.	Name	Туре	Description		
1	USBDM	INPUT	USB Data Signal Minus.		
10	USBDP	INPUT	USB Data Signal Plus.		
2	RESET#	INPUT	Reset input (active low).		

Table 3.2 Common Function pins

^{*}Pin 11 is the centre pad on the chip package base. This should be connected to GND



Version 1.3

Document No.: FT_000628 Clearance No.: FTDI# 265

Pin No.	Name	Туре	Description		
8	SDA	I/O	I ² C bi-directional data line. The signal is open drain.		
6	SCL	Input	I ² C clock input		
5	CBUS0	I/O	Configurable CBUS I/O Pin. Function of this pin is configured in the device MTP memory. See CBUS Signal Options, Table 3.4.		

Table 3.3 I²C Interface and CBUS Group (see note 1)

Note:

- 1. When used in Input Mode, the input pins are pulled to VCCIO via internal $75k\Omega$ (approx) resistors. These pins can be programmed to gently pull low during USB suspend (PWREN# = "1") by setting an option in the MTP memory.
- 2. Clock stretching is not supported

Version 1.3

Document No.: FT_000628 Clearance No.: FTDI# 265

3.2 CBUS Signal Options

The following options can be configured on the CBUS I/O pins. These options can be configured in the internal MTP memory using the software utility FT_PROG, which can be downloaded from the FTDI Utilities (www.ftdichip.com). The default configuration is noted below and described in Section 10.

CBUS Signal Option	Available On CBUS Pin	Description	
TRI-STATE	CBUS0	IO Pad is tri-stated	
DRIVE 1	CBUS0	Output a constant 1	
DRIVE 0	CBUS0	Output a constant 0	
PWREN#	CBUS0	Output is low after the device has been configured by USB, then high during USB suspend mode. This output can be used to control power to external logic P-Channel logic level MOSFET switch. Enable the interface pull-down option when using the PWREN# in this way.	
SLEEP#	CBUS0	Goes low during USB suspend mode. Typically used to power down an external logic to reduce power consumption.	
CLK24MHz	CBUS0	24 MHz Clock output.*	
CLK12MHz	CBUS0	12 MHz Clock output.*	
CLK6MHz	CBUS0	6 MHz Clock output.*	
GPIO	CBUS0	CBUS bit bang mode option A separate application note, AN232R-01, available from FTDI website(www.ftdichip.com) describes in more detail how to use CBUS bit bang mode.	
BCD Charger	CBUS0	Battery Charge Detect, indicates when the device is connected to a dedicated battery charger host. Active high output.	
BCD Charger#	CBUS0	Inverse of BCD Charger (open drain)	
BitBang_WR#	CBUS0	Synchronous and asynchronous bit bang mode WR# strobe output.	
BitBang_RD#	CBUS0	Synchronous and asynchronous bit bang mode RD# strobe output.	
I2C_TXE#	CBUS0	Transmit buffer empty, used to indicate to $\text{\rm I}^2\text{\rm C}$ master device status of the FT200XDtransmit buffer	
I2C_RXF#	CBUS0	Receive buffer full, used to indicate to $\ensuremath{\mathrm{I}}^2\ensuremath{\mathrm{C}}$ master device status of FT200XD receive buffer	
VBUS Sense	CBUS0	Input to detect when VBUS is present.	
Time Stamp	CBUS0	Toggle signal which changes state each time a USB SOF is received	
Keep_Awake#	CBUS0	Prevents the device from entering suspend state when unplugged. May be used if programming the MTP memory over ${\rm I}^2{\rm C}$	

Table 3.4 CBUS Configuration Control

^{*}When in USB suspend mode the outputs clocks are also suspended.



Version 1.3

Document No.: FT_000628 Clearance No.: FTDI# 265

4 Function Description

The FT200XD is a package and pin optimised USB to I^2C interface device which simplifies USB to I^2C designs and reduces external component count by fully integrating an external EEPROM and a clock circuit which requires no external crystal in a small form factor $3x3mm\ 10$ pin package. It has been designed to operate efficiently with a USB host controller by using as little of the total USB bandwidth available as possible.

4.1 Key Features

Functional Integration. Fully integrated MTP memory, clock generation, AVCC filtering, Power-On Reset (POR) and LDO regulators.

Configurable CBUS I/O Pin Options. The fully integrated MTP memory allows configuration of the Control Bus (CBUS) functionality and drive strength selection. There is 1 configurable CBUS I/O pin. These configurable options are defined in section 3.2.

The device is supplied with the most commonly used pin definitions pre-programmed - see Section 10 for details.

Asynchronous Bit Bang Mode with RD# and WR# Strobes. The FT200XD supports FTDI's previous chip generation bit-bang mode. In bit-bang mode, the 2 I²C lines can be switched from the regular interface mode to a 2-bit general purpose I/O port. Data packets can be sent to the device and they will be sequentially sent to the interface at a rate controlled by an internal timer (equivalent to the baud rate pre-scalar). In the FT200XD device this mode has been enhanced by outputting the internal RD# and WR# strobes signals which can be used to allow external logic to be clocked by accesses to the bit-bang I/O bus. This option will be described more fully in a separate application note available from FTDI website (www.ftdichip.com).

Synchronous Bit Bang Mode. The FT200XD supports synchronous bit bang mode. This mode differs from asynchronous bit bang mode in that the interface pins are only read when the device is written to. This makes it easier for the controlling program to measure the response to an output stimulus as the data returned is synchronous to the output data. An application note, AN232R-01, available from FTDI website(www.ftdichip.com) describes this feature.

Low Power Consumption, The FT200XD is capable of operating at a voltage supply between +3.3V and +5V with a nominal operational mode current of 8mA and a nominal USB suspend mode current of 125μ A. This allows greater margin for peripheral designs to meet the USB suspend mode current limit of 2.5mA. An integrated level converter within the I^2 C interface allows the FT200XD to interface to I^2 C logic running at +1.8V to +3.3V (5V tolerant).

4.2 Functional Block Descriptions

The following paragraphs detail each function within the FT200XD. Please refer to the block diagram shown in Figure 2.1.

Internal MTP Memory. The internal MTP memory in the FT200XD is used to store USB Vendor ID (VID), Product ID (PID), device serial number, product description string and various other USB configuration descriptors. The internal MTP memory is also used to configure the CBUS pin functions. The FT200XD is supplied with the internal MTP memory pre-programmed as described in Section10. A user area of the internal MTP memory is available to system designers to allow storing of additional data from the user application over USB. The internal MTP memory descriptors can be programmed in circuit, over USB without any additional programming voltage requirements. The descriptors can be programmed using the FTDI utility software called FT_PROG, which can be downloaded from FTDI Utilitieson the FTDI website (www.ftdichip.com). Additionally the MTP memory can be configured over the $\rm I^2C$ interface.

- **+1.8V LDO Regulator.** The +1.8V LDO regulator generates the +1.8V reference voltage for driving the internal core of the IC.
- **+3.3V LDO Regulator.** The +3.3V LDO regulator generates the +3.3V reference voltage for driving the USB transceiver cell output buffers. It requires an external decoupling capacitor to be connected to the 3V3OUT regulator output pin. It also provides +3.3V power to the $1.5k\Omega$ internal pull up resistor on USBDP. The main function of the LDO is to power the USB Transceiver and the Reset Generator Cells rather than to power external logic. However, it can be used to supply external circuitry requiring a +3.3V nominal supply with a maximum current of 50mA.

USB Transceiver. The USB Transceiver Cell provides the USB 1.1 / USB 2.0 full-speed physical interface to the USB cable. The output drivers provide +3.3V level slew rate control signalling, whilst a differential



Version 1.3

Document No.: FT_000628 Clearance No.: FTDI# 265

input receiver and two single ended input receivers provide USB data in, Single-Ended-0 (SE0) and USB reset detection conditions respectfully. This function also incorporates a $1.5k\Omega$ pull up resistor on USBDP. The block also detects when connected to a USB power supply which will not enumerate the device but still supply power and may be used for battery charging.

USB DPLL. The USB DPLL cell locks on to the incoming NRZI USB data and generates recovered clock and data signals for the Serial Interface Engine (SIE) block.

Internal 12MHz Oscillator - The Internal 12MHz Oscillator cell generates a 12MHz reference clock. This provides an input to the x4 Clock Multiplier function. The 12MHz Oscillator is also used as the reference clock for the SIE, USB Protocol Engine and UART FIFO controller blocks.

Clock Multiplier / Divider. The Clock Multiplier / Divider takes the 12MHz input from the Internal Oscillator function and generates the 48MHz, 24MHz, 12MHz and 6MHz reference clock signals. The 48MHz clock reference is used by the USB DPLL and the Baud Rate Generator blocks.

Serial Interface Engine (SIE). The Serial Interface Engine (SIE) block performs the parallel to serial and serial to parallel conversion of the USB data. In accordance with the USB 2.0 specification, it performs bit stuffing/un-stuffing and CRC5/CRC16 generation. It also checks the CRC on the USB data stream.

USB Protocol Engine. The USB Protocol Engine manages the data stream from the device USB control endpoint. It handles the low level USB protocol requests generated by the USB host controller and the commands for controlling the functional parameters of the I^2C in accordance with the USB 2.0 specification chapter 9.

FIFO RX Buffer (512 bytes). Data sent from the USB host controller to the I2C interface via the USB data OUT endpoint is stored in the FIFO RX (receive) buffer. Data is removed from the buffer to the I2C transmit register under control of the I2C Controller.(RX is relative to the USB interface).

FIFO TX Buffer (512 bytes). Data from the I²C receive register is stored in the TX buffer. The USB host controller removes data from the FIFO TX Buffer by sending a USB request for data from the device data IN endpoint.(TX is relative to the USB interface).

 I^2C Controller. Module to handle the latching in and out of serial data on the I^2C interface. Supports up to 3.4MHz, High Speed Serial Mode.

RESET Generator - The integrated Reset Generator Cell provides a reliable power-on reset to the device internal circuitry at power up. The RESET# input pin allows an external device to reset the FT200XD.

RESET# can be tied to 3V3OUT.



Version 1.3

Document No.: FT_000628 Clearance No.: FTDI# 265

5 I²C Interface Description

 I^2C (Inter Integrated Circuit) is a multi-master serial bus invented by Philips. I^2C uses two bi-directional open-drain wires called serial data (SDA) and serial clock (SCL). Common I^2C bus speeds are the 100 kbit/s standard mode (SM), 400 kbit/s fast mode (FM), 1 Mbit/s Fast mode plus (FM+), and 3.4 Mbit/s High Speed mode (HS)

An I²C bus node can operate either as a master or a slave:

- Master node issues the clock and addresses slaves
- Slave node receives the clock line and address.

The FT200XD device only operates as a slave, and is capable of speeds up to 3.4MBit/s. There are four potential modes of operation for a given bus device, although most devices only use a single role (Master or Slave) and its two modes (Transmit and Receive):

- Master transmit sending data to a slave
- Master receive receiving data from a slave
- Slave transmit sending data to a master
- Slave receive receiving data from the master

The master is initially in master transmit mode by sending a start bit followed by the 7-bit address of the slave it wishes to communicate with, which is finally followed by a single bit representing whether it wishes to write(0) to or read(1) from the slave.

If the slave exists on the bus then it will respond with an ACK bit (active low for acknowledged) for that address. The master then continues in either transmit or receive mode (according to the read/write bit it sent), and the slave continues in its complementary mode (receive or transmit, respectively).

The address and the data bytes are sent most significant bit first. The start bit is indicated by a high-to-low transition of SDA with SCL high; the stop bit is indicated by a low-to-high transition of SDA with SCL high.

If the master wishes to write to the slave then it repeatedly sends a byte with the slave sending an ACK bit. (In this situation, the master is in master transmit mode and the slave is in slave receive mode.)

If the master wishes to read from the slave then it repeatedly receives a byte from the slave, the master sends an ACK bit after every byte but the last one. (In this situation, the master is in master receive mode and the slave is in slave transmit mode.)

The master then ends transmission with a stop bit, or it may send another START bit if it wishes to retain control of the bus for another transfer (a "combined message").

I²C defines three basic types of message, each of which begins with a START and ends with a STOP:

- Single message where a master writes data to a slave;
- Single message where a master reads data from a slave;
- Combined messages, where a master issues at least two reads and/or writes to one or more slaves

In a combined message, each read or write begins with a START and the slave address. After the first START, these are also called repeated START bits; repeated START bits are not preceded by STOP bits, which is how slaves know the next transfer is part of the same message.

Please refer to the I²C specification for more information on the protocol.

Document No.: FT_000628 Clearance No.: FTDI# 265

6 Devices Characteristics and Ratings

6.1 Absolute Maximum Ratings

The absolute maximum ratings for the FT200XD devices are as follows. These are in accordance with the Absolute Maximum Rating System (IEC 60134). Exceeding these may cause permanent damage to the device.

Parameter	Value	Unit	Conditions
Storage Temperature	-65°C to 150°C	Degrees C	
Floor Life (Out of Bag) At Factory Ambient (30°C / 60% Relative Humidity)	168 Hours (IPC/JEDEC J- STD-033A MSL Level 3 Compliant)*	Hours	
Ambient Operating Temperature (Power Applied)	-40°C to 85°C	Degrees C	
MTTF FT200XD	TBD	Hours	
MTTF FT200XD	TBD	Hours	
VCC Supply Voltage	-0.3 to +5.5	V	
VCCIO IO Voltage	-0.3 to +4.0	V	
DC Input Voltage – USBDP and USBDM	-0.5 to +3.63	V	
DC Input Voltage – High Impedance Bi-directionals (powered from VCCIO)	-0.3 to +5.8	V	
DC Output Current – Outputs	22	mA	

Table 6.1 Absolute Maximum Ratings

6.2 ESD and Latch-up Specifications

Description	Specification		
Human Body Mode (HBM)	> ± 2kV		
Machine mode (MM)	> ± 200V		
Charged Device Mode (CDM)	> ± 500V		
Latch-up	> ± 200mA		

Table 6.2 ESD and Latch-Up Specifications

^{*} If devices are stored out of the packaging beyond this time limit the devices should be baked before use. The devices should be ramped up to a temperature of +125°C and baked for up to 17 hours.

Version 1.3
Document No.: FT_000628 Clearance No.: FTDI# 265

6.3 DC Characteristics

DC Characteristics (Ambient Temperature = -40°C to +85°C)

Parameter	Description	Minimum	Typical	Maximum	Units	Conditions
VCC	VCC Operating Supply Voltage	2.97	5	5.5	V	Normal Operation
VCC2	VCCIO Operating Supply Voltage	1.62		3.63	V	
Icc1	Operating Supply Current	6.8	8	9.1	mA	Normal Operation
Icc2	Operating Supply Current		125		μA	USB Suspend
3V3	3.3v regulator output	2.97	3.3	3.63	V	VCC must be greater than 3V3 otherwise 3V3OUT is an input which must be driven with 3.3V in this instance pins 3 and 4 of the package should be shorted together.

Table 6.3 Operating Voltage and Current

Version 1.3

Document No.: FT_000628 Clearance No.: FTDI# 265

Parameter	Description	Minimum	Typical	Maximum	Units	Conditions
		2.97	VCCIO	VCCIO	V	Ioh =-2mA I/O Drive strength* = 4mA
Voh	Output Voltage High	2.97	VCCIO	VCCIO	V	I/O Drive strength* = 8mA
		2.97	VCCIO	VCCIO	V	I/O Drive strength* = 12mA
		2.97	VCCIO	VCCIO	V	I/O Drive strength* = 16mA
			0	0.4	V	Iol = +2mA I/O Drive strength* = 4mA
Vol	Output Voltage Low		0	0.4	V	I/O Drive strength* = 8mA
			0	0.4	V	I/O Drive strength* = 12mA
			0	0.4	V	I/O Drive strength* = 16mA
Vil	Input low Switching Threshold			0.8	V	LVTTL
Vih	Input High Switching Threshold	2.0			V	LVTTL
Vt	Switching Threshold		1.49		V	LVTTL
Vt-	Schmitt trigger negative going threshold voltage		1.15		V	
Vt+	Schmitt trigger positive going threshold voltage		1.64		V	
Rpu	Input pull-up resistance	40	75	190	ΚΩ	Vin = 0
Rpd	Input pull-down resistance	40	75	190	ΚΩ	Vin =VCCIO
Iin	Input Leakage Current	-10	+/-1	10	μΑ	Vin = 0
Ioz	Tri-state output leakage current	-10	+/-1	10	μΑ	Vin = 5.5V or 0

Table 6.4 I/O Pin Characteristics VCCIO = +3.3V (except USB PHY pins)

* The I/O drive strength and slow slew-rate are configurable in the MTP memory.



Version 1.3
Document No.: FT_000628 Clearance No.: FTDI# 265

Parameter	Description	Minimum	Typical	Maximum	Units	Conditions
		2.25	VCCIO	VCCIO	V	Ioh = +/-2mA I/O Drive strength* = 4mA
Voh	Output Voltage High	2.25	VCCIO	VCCIO	V	I/O Drive strength* = 8mA
		2.25	VCCIO	VCCIO	V	I/O Drive strength* = 12mA
		2.25	VCCIO	VCCIO	V	I/O Drive strength* = 16mA
			0	0.4	V	Iol = +/-2mA I/O Drive strength* = 4mA
Vol	Output Voltage Low		0	0.4	V	I/O Drive strength* = 8mA
			0	0.4	V	I/O Drive strength* = 12mA
			0	0.4	V	I/O Drive strength* = 16mA
Vil	Input low Switching Threshold			0.8	V	LVTTL
Vih	Input High Switching Threshold	0.8			V	LVTTL
Vt	Switching Threshold		1.1		V	LVTTL
Vt-	Schmitt trigger negative going threshold voltage		0.8		V	
Vt+	Schmitt trigger positive going threshold voltage		1.2		V	
Rpu	Input pull-up resistance	40	75	190	ΚΩ	Vin = 0
Rpd	Input pull-down resistance	40	75	190	ΚΩ	Vin =VCCIO
Iin	Input Leakage Current	-10	+/-1	10	μΑ	Vin = 0
Ioz	Tri-state output leakage current	-10	+/-1	10	μА	Vin = 5.5V or 0

Table 6.5 I/O Pin Characteristics VCCIO = +2.5V (except USB PHY pins)

* The I/O drive strength and slow slew-rate are configurable in the MTP memory.



Version 1.3

Document No.: FT_000628 Clearance No.: FTDI# 265

Parameter	Description	Minimum	Typical	Maximum	Units	Conditions
		1.62	VCCIO	VCCIO	V	Ioh = +/-2mA I/O Drive strength* = 4mA
Voh	Output Voltage High	1.62	VCCIO	VCCIO	V	I/O Drive strength* = 8mA
		1.62	VCCIO	VCCIO	V	I/O Drive strength* = 12mA
		1.62	VCCIO	VCCIO	V	I/O Drive strength* = 16mA
	Vol Output Voltage Low		0	0.4	V	Iol = +/-2mA I/O Drive strength* = 4mA
Vol			0	0.4	V	I/O Drive strength* = 8mA
			0	0.4	V	I/O Drive strength* = 12mA
			0	0.4	V	I/O Drive strength* = 16mA
Vil	Input low Switching Threshold			0.77	V	LVTTL
Vih	Input High Switching Threshold	1.6			V	LVTTL
Vt	Switching Threshold		0.77		V	LVTTL
Vt-	Schmitt trigger negative going threshold voltage		0.557		V	
Vt+	Schmitt trigger positive going threshold voltage		0.893		V	
Rpu	Input pull-up resistance	40	75	190	ΚΩ	Vin = 0
Rpd	Input pull-down resistance	40	75	190	ΚΩ	Vin =VCCIO
Iin	Input Leakage Current	-10	+/-1	10	μΑ	Vin = 0
Ioz	Tri-state output leakage current	-10	+/-1	10	μА	Vin = 5.5V or 0

Table 6.6 I/O Pin Characteristics VCCIO = +1.8V (except USB PHY pins)

* The I/O drive strength and slow slew-rate are configurable in the MTP memory.





Parameter	Description	Minimum	Typical	Maximum	Units	Conditions
Voh	Output Voltage High	VCC-0.2			V	
Vol	Output Voltage Low			0.2	V	
Vil	Input low Switching Threshold		-	0.8	V	
Vih	Input High Switching Threshold	2.0	-		V	

Table 6.7 USB I/O Pin (USBDP, USBDM) Characteristics

6.4 MTP Memory Reliability Characteristics

The internal 2048 Byte MTP Memory has the following reliability characteristics:

Parameter	Value	Unit
Data Retention	10	Years
Write Cycle	2,000 minimum	Cycles
Read Cycle	Unlimited	Cycles

Table 6.8 MTP Memory Characteristics

6.5 Internal Clock Characteristics

The internal Clock Oscillator has the following characteristics:

Parameter		Unit			
rarameter	Minimum	Typical	Maximum	O.I.I.C	
Frequency of Operation (see Note 1)	11.98	12.00	12.02	MHz	
Clock Period	83.19	83.33	83.47	ns	
Duty Cycle	45	50	55	%	

Table 6.9 Internal Clock Characteristics

Note 1: Equivalent to +/-1667ppm

Version 1.3
Document No.: FT 000628 Clearance No.: FTDI# 265

7 USB Power Configurations

The following sections illustrate possible USB power configurations for the FT200XD.

7.1 USB Bus Powered Configuration

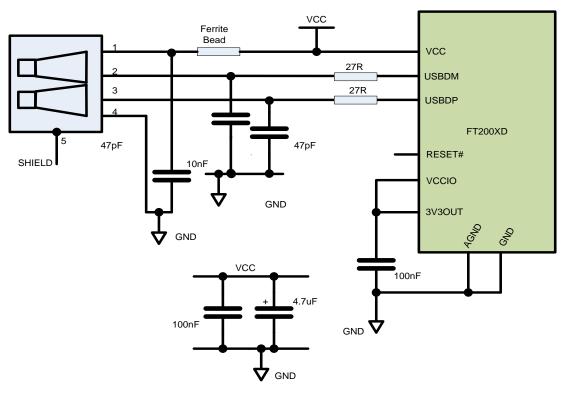


Figure 7.1 Bus Powered Configuration

Figure 7.1Illustrates the FT200XD in a typical USB bus powered design configuration. A USB bus powered device gets its power from the USB bus. Basic rules for USB bus power devices are as follows –

- i) On plug-in to USB, the device must draw no more current than 100mA.
- ii) In USB Suspend mode the device must draw no more than 2.5mA.
- A bus powered high power USB device (one that draws more than 100mA) should use the CBUS pins configured as PWREN# and use it to keep the current below 100mA on plug-in and 2.5mA on USB suspend. Using the CBUS pin for PWREN# prevents the FT200XD from indicating a USB Battery Charger is connected.
- iv) A device that consumes more than 100mA cannot be plugged into a USB bus powered hub.
- v) No device can draw more than 500mA from the USB bus.

The power descriptors in the internal MTP Memory of the FT200XDmustbe programmed to match the current drawn by the device.

A ferrite bead is connected in series with the USB power supply to reduce EMI noise from the FT200XD and associated circuitry being radiated down the USB cable to the USB host. The value of the Ferrite Bead depends on the total current drawn by the application. A suitable range of Ferrite Beads is available from Laird Technologies (http://www.lairdtech.com), for example Laird Technologies Part # MI0805K601R-10.

Note: If using PWREN# (available using the CBUS) the pin must be pulled to VCCIO using a $10k\Omega$ resistor.

Version 1.3

Document No.: FT_000628 Clearance No.: FTDI# 265

7.2 Self Powered Configuration

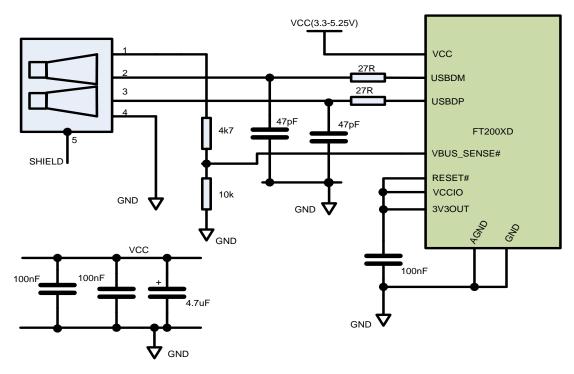


Figure 7.2 Self Powered Configuration

Figure 7.2 illustrates the FT200XD in a typical USB self powered configuration. A USB self powered device gets its power from its own power supply, VCC, and does not draw current from the USB bus. The basic rules for USB self powered devices are as follows –

- i) A self powered device must not force current down the USB bus when the USB host or hub controller is powered down.
- ii) A self powered device can use as much current as it needs during normal operation and USB suspend as it has its own power supply.
- iii) A self powered device can be used with any USB host, a bus powered USB hub or a self powered USB hub.

The power descriptor in the internal MTP memory of the FT200XD should be programmed to a value of zero (self powered).

In order to comply with the first requirement above, the USB bus power (pin 1) is used to control the VBUS_Sense pin of the FT200XD device. When the USB host or hub is powered up an internal $1.5k\Omega$ resistor on USBDP is pulled up to +3.3V, thus identifying the device as a full speed device to the USB host or hub. When the USB host or hub is powered off, VBUS_Sense pin will be low and the FT200XDis held in a suspend state. In this state the internal $1.5k\Omega$ resistor is not pulled up to any power supply (hub or host is powered down), so no current flows down USBDP via the $1.5k\Omega$ pull-up resistor. Failure to do this may cause some USB host or hub controllers to power up erratically.

Figure 7.2 illustrates a self powered design which has a +3.3V to +5.25V supply.

Note:

1. When the FT200XD is in reset, the interface I/O pins are tri-stated. Input pins have internal $200k\Omega$ pull-up resistors to VCCIO, so they will gently pull high unless driven by some external logic.



Document No.: FT_000628 Clearance No.: FTDI# 265

7.3 USB Bus Powered with Power Switching Configuration

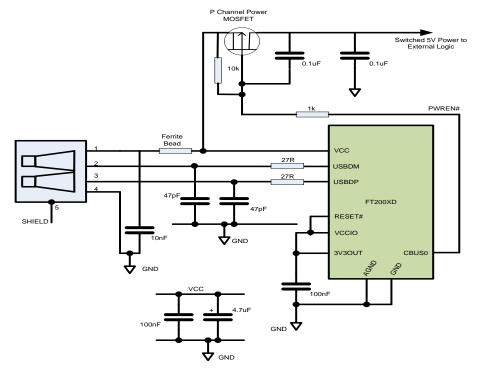


Figure 7.3 Bus Powered with Power Switching Configuration

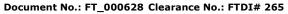
A requirement of USB bus powered applications, is when in USB suspend mode, the application draws a total current of less than 2.5mA. This requirement includes external logic. Some external logic has the ability to power itself down into a low current state by monitoring the PWREN# signal. For external logic that cannot power itself down in this way, the FT200XD provides a simple but effective method of turning off power during the USB suspend mode.

Figure 7.3 shows an example of using a discrete P-Channel MOSFET to control the power to external logic. A suitable device to do this is an International Rectifier (www.irf.com) IRLML6402, or equivalent. It is recommended that a "soft start" circuit consisting of a $1k\Omega$ series resistor and a $0.1\mu\text{F}$ capacitor is used to limit the current surge when the MOSFET turns on. Without the soft start circuit it is possible that the transient power surge, caused when the MOSFET switches on, will reset the FT200XD or the USB host/hub controller. The soft start circuit example shown in Figure 7.3 powers up with a slew rate of approximaely12.5V/ms. Thus supply voltage to external logic transitions from GND to +5V in approximately 400 microseconds.

As an alternative to the MOSFET, a dedicated power switch IC with inbuilt "soft-start" can be used. A suitable power switch IC for such an application is the Micrel (www.micrel.com) MIC2025-2BM or equivalent.

With power switching controlled designs the following should be noted:

- i) The external logic to which the power is being switched should have its own reset circuitry to automatically reset the logic when power is re-applied when moving out of suspend mode.
- ii) Set the Pull-down on Suspend option in the internal FT200XD MTP memory.
- iii) The CBUS Pin should be configured as PWREN# in the internal FT200XD MTP memory, and used to switch the power supply to the external circuitry. Detection of a USB battery charger port is not possible.
- iv) For USB high-power bus powered applications (one that consumes greater than 100mA, and up to 500mA of current from the USB bus), the power consumption of the application must be set in the Max Power field in the internal FT200XD MTP memory. A high-power bus powered application uses the descriptor in the internal FT200XD MTP memory to inform the system of its power requirements.
- v) PWREN# gets its VCC from VCCIO. For designs using 3V3 logic, ensure VCCIO is not powered down using the external logic. In this case use the +3V3OUT.





8 Application Examples

The following sections illustrate possible applications of the FT200XD.

8.1 USB to I²C Converter

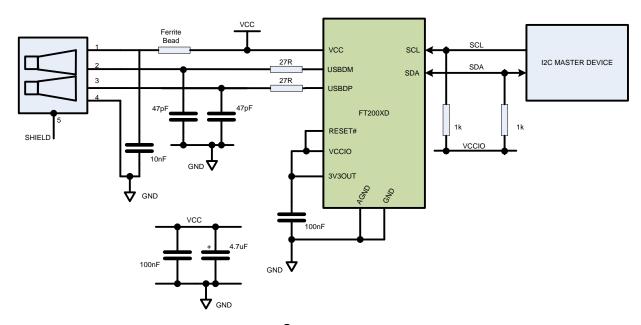


Figure 8.1 Application Example showing USB to I²C Converter

An example of using the FT200XD as an I^2 C peripheral is shown in Figure 8.1. The FT200XD is the slave on the I^2 C bus.

Therefore the clock supplied to the SCL pin must come from the I^2C Master. The device will support standard I^2C data rates such as 100 kbit/s standard mode (SM), 400 kbit/s fast mode (FM), 1 Mbit/s Fast mode plus (FM+), and 3.4 Mbit/s High Speed mode (HS).

The data line SDA is bi-directional.

The master is initially in master transmit mode by sending a start bit followed by the 7-bit address of the slave it wishes to communicate with, which is finally followed by a single bit representing whether it wishes to write(0) to or read(1) from the slave.

If the slave (FT200XD) exists on the bus then it will respond with an ACK bit (active low for acknowledged) for that address. The master then continues in either transmit or receive mode (according to the read/write bit it sent), and the slave continues in its complementary mode (receive or transmit, respectively).

The address and the data bytes are sent most significant bit first. The start bit is indicated by a high-to-low transition of SDA with SCL high; the stop bit is indicated by a low-to-high transition of SDA with SCL high.

If the master wishes to write to the slave then it repeatedly sends a byte with the slave sending an ACK bit. (In this situation, the master is in master transmit mode and the slave is in slave receive mode.)

If the master wishes to read from the slave then it repeatedly receives a byte from the slave, the master sending an ACK bit after every byte but the last one. (In this situation, the master is in master receive mode and the slave is in slave transmit mode.)

The master then ends transmission with a stop bit, or it may send another START bit if it wishes to retain control of the bus for another transfer (a "combined message").

I²C defines three basic types of message, each of which begins with a START and ends with a STOP:

- Single message where a master writes data to a slave;
- Single message where a master reads data from a slave;

Document No.: FT_000628 Clearance No.: FTDI# 265

 Combined messages, where a master issues at least two reads and/or writes to one or more slaves

In a combined message, each read or write begins with a START and the slave address. After the first START, these are also called repeated START bits; repeated START bits are not preceded by STOP bits, which is how slaves know the next transfer is part of the same message.

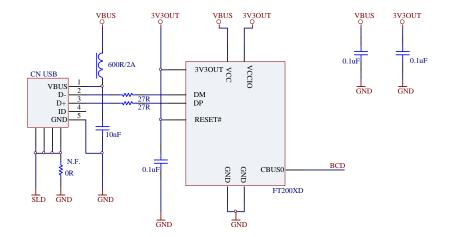
The I^2C address of the FT200XD is stored in the device internal MTP memory.

Please refer to the I²C specification for more information on the protocol.

8.2 USB Battery Charging Detection

A recent addition to the USB specification

(http://www.usb.org/developers/devclass docs/BCv1.2 011912.zip) is to allow for additional charging profiles to be used for charging batteries in portable devices. These charging profiles do not enumerate the USB port of the peripheral. The FT200XD device will detect that a USB compliant dedicated charging port (DCP) is connected. Once detected while in suspend mode a battery charge detection signal is provided to allow external logic to switch to charging mode as opposed to operation mode.



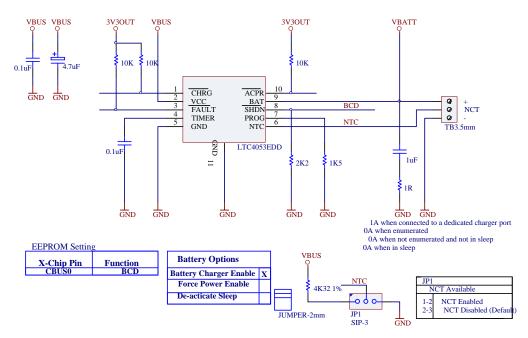


Figure 8.2 USB Battery Charging Detection

To use the FT200XD with battery charging detection the CBUS pins must be reprogrammed to allow for the BCD Charger output to switch the external charger circuitry on. The CBUS pins are configured in the



Version 1.3

Document No.: FT_000628 Clearance No.: FTDI# 265

internal MTP memory with the free utility FTPROG. If the charging circuitry requires an active low signal to enable it, the CBUS pin can be programmed to BCD Charger# as an alternative.

When connected to a USB compliant dedicated charging port (DCP, as opposed to a standard USB host) the device USB signals will be shorted together and the device suspended. The BCD charger signal will bring the LTC4053 out of suspend and allow battery charging to start. The charge current in the example above is 1A as defined by the resistance on the PROG pin.

To calculate the equivalent resistance on the PROG pin select a charge current, then Res = $1500V/I_{chg}$ For more configuration options of the LTC4053 refer to:

AN_175_Battery Charging Over USB

Note: If the FT200XD is connected to a standard host port such that the device is enumerated the battery charge detection signal is inactive as the device will not be in suspend.



Version 1.3

Document No.: FT_000628 Clearance No.: FTDI# 265

9 USB and I²C Interfacing

This section covers the transfer of data from USB to I²C and vice versa.

Please note that the FT200XD and FT201X are I^2C slave devices only and should be interfaced to an I^2C host (often in a microcontroller or FPGA). If an I^2C master is required, please see the FT232H, FT2232H, FT4232H and FT2232D devices.

This section covers transfer of data only. The USB and I^2C interfaces on the FT200XD and FT201X can also be used for programming of the MTP memory, which is covered in a separate section.

Throughout this section, the reference FT-X applies to the FT200XD and FT201X devices, as the other members of the FT-X family do not have I^2C interfaces.

9.1 Host Interface (USB)

From the host computer's point of view, the I^2C data can be sent and received in the same way as when interfacing to one of the standard UART devices such as the FT232R. The FT-X handles the entire I^2C protocol inside the chip and so reading and writing data does not require any special programming from the PC side. It can be treated as a simple data bridge.

9.1.1 VCP and D2xx Interfaces

Like the other FTDI devices, the host can use D2xx commands or can use a Virtual COM Port (VCP) to communicate with the device.

D2xx Interface

The D2xx method allows the application software to use the functions in the FTDI D2xx library to communicate directly with the device. This is a library provided free-of-charge by FTDI and is available within the driver download files at the link below.

http://www.ftdichip.com/Drivers/D2XX.htm

It includes functions to find the FTDI devices on the system, open a particular device, send data to the device and read data from the device. Any data written using FT_Write, for example, will be sent to the FT-X chip and will be available for the external I^2C Master to read. As mentioned above, only the data itself needs to be sent as the FT-X handles all of the I^2C specific protocol.

There are many other functions available, and full details can be found in the D2xx Programmers Guide.

http://www.ftdichip.com/Support/Documents/ProgramGuides/D2XX_Programmer's_Guide(FT_000071).pd f

Virtual COM Port Interface

If using the Virtual Com Port (VCP), the device will appear as if it were a real COM port on the computer. This is useful where an application has already been written to use an RS232 port on the computer as it allows that application to treat the FT-X as if it were a real COM port. This port can be opened in a terminal program or a custom application in the same way as a serial port would be opened. Data can then be sent or received using standard serial / COM port functions.

No I^2C decoding is required as the chip itself handles the I^2C protocol. Because of this, even I^2C versions of the FT-X family can be used with the VCP interface. Any data which the host PC sends to the Virtual COM Port (for example, typed into the terminal window in HyperTerminal) will be sent over USB to the FT-X and can then be read by the external I^2C Master. Likewise, any data written to the FT-X over I^2C will be sent to the PC where the terminal program will display it.

Since the FT-X is the I^2C slave and does not generate a clock signal, the settings such as baud rate and handshaking do not have any effect.



Version 1.3

Document No.: FT_000628 Clearance No.: FTDI# 265

D2xx and VCP Interface under Windows

In Windows systems, the VCP driver is actually an additional layer on top of the D2xx driver. The D2xx driver is always loaded and the VCP later may or may not be loaded on top of it, depending on the requirements of the application.

When VCP is disabled, the device will appear only under Universal Serial Bus Controllers in the Device Manager and no COM port is exposed. When the VCP is enabled, the device will appear under both the Universal Serial Bus Controllers and the Ports (COM & LPT) sections in Device Manager.

The VCP interface will be disabled by default in the FT200XD and FT201X but can be enabled in one of the following ways:

- An option bit in the MTP memory on the chip is checked each time that the device is enumerated, and can cause the host computer to load the VCP layer. This allows each individual hardware unit to enable or disable VCP as per it's requirements. The MTP information in section 10 has further details. FT Prog can also be used to modify the MTP settings.
- The user may open the Properties for the device under Universal Serial Bus Controllers in Device Manager in Windows and tick a box to load the VCP. Re-enumeration of the FT-X is necessary to enable the new setting.
- By editing the driver FtdiBus.inf file (please refer to AN_107 below). Note that the FT_INF utility available from the FTDI website can be used to help create the modifed inf files.
 http://www.ftdichip.com/Support/Documents/AppNotes/AN_107_AdvancedDriverOptions_AN_00_0073.pdf

In other Operating systems (e.g. Linux, Mac and Windows CE), there are separate drivers for D2xx and VCP, and only one of these drivers may be installed at any time. Therfore, the mode is selected by installing the associated driver instead and the selection defined in the bullet points above has no effect.

9.1.2 Reading and Writing Data

Data from FT-X to the Host

When data is to be sent from the host computer to the external I^2C master, the software application writes this data to the FTDI driver using VCP or D2xx and this data is sent by the driver over USB to the buffer in the device.

The external I^2C master device may then perform an I^2C read (Master receiver, Slave transmitter) operation to retrieve the data.

The external I^2C master should check if data is available to ensure that the data which has been read is valid. The methods for this are described in section 9.2.2 below.

Data from Host to the FT-X

When data is to be sent from the external I^2C master to the host computer, the external master performs an I^2C write (Master transmitter, Slave receiver) operation to the FT-X.

The FT-X stores this in its buffer and the data is sent back to the driver on the host computer over USB. As with other FTDI devices, this happens when either the buffer in the device fills or when the latency timer rolls over (so that partially filled buffers do not wait indefinitely), whichever happens first.

Note that when writing data to the FT-X over I^2C , the external master should check whether there is space available in the buffer inside the FT-X. It can do this using the methods shown in section 9.2.2 below.

The host computer application can then read the data from the driver buffer using the VCP interface or the D2xx commands. In the case of D2xx, the number of bytes available may be determined using the FT GetQueueStatus command before doing the FT Read.

Version 1.3

Document No.: FT_000628 Clearance No.: FTDI# 265

9.2 I²C Interface

From an I^2C point of view, the FT-X behaves as a standard I^2C slave. Data transfers take the same form as a standard I^2C communication. In addition to reading and writing, there are some other commands which can be used to determine the status of the device and these are covered in this section and in further detail in section 9.3.

Note: This section uses 7-bit addressing in the examples. It uses eight characters to describe the seven address bits and the single read/write bit. For example, 1110 011 1 means address 0x73 with the Read/Write bit set to 1, and therefore corresponds to a read of address 0x73. Data values are represented in bytes, for example, 1010 0101 for data value 0xA5.

9.2.1 Addressing

The FT-X can be given a custom slave address on the I^2C bus. This is stored in MTP memory and can be re-programmed over USB or I^2C . Please see the separate MTP Programming information in section 10. The slave address is used when reading and writing to the device. The FT-X supports both 7-bit and 10-bit addressing.

The general call address (0000 000 0) is for addressing every device on the bus. Some slaves do not support the General Call Address though the FT-X devices do support it. They will acknowledge this address, receive the second byte and interpret it. There are several commands available for this second byte. The FT-X will support the Software Reset command which is part of the I2C specification as well as other custom FTDI commands. These are covered in more detail later in the Other I2C Commands section.

9.2.2 Data Transfers

Reading and Writing

For all I^2C data transfers to and from the FT-X, the slave address of the FT-X is used. The figure below shows a typical 7-bit address transfer for each direction.

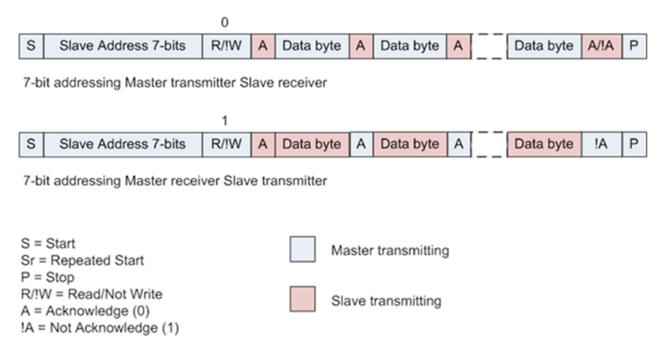


Figure 9.1: Data transfers using 7-bit addressing

The figure below summarises all of the transfers available (7-bit and 10-bit addressing).

Version 1.3

Document No.: FT_000628 Clearance No.: FTDI# 265

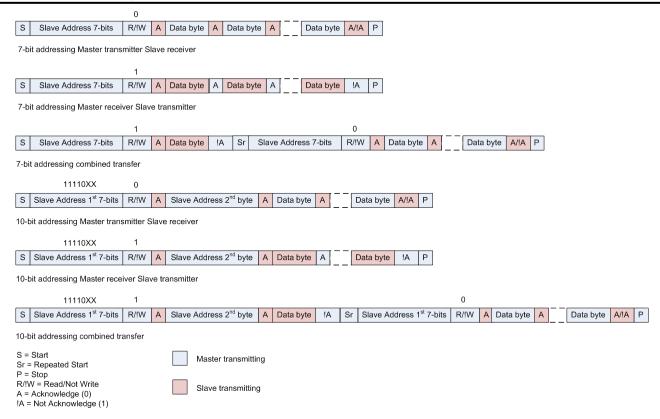


Figure 9.2: Data transfers with 7-bit and 10-bit addressing modes

Flow Control when Reading

When reading data, it is important to know if there is data available to read over I^2C and if the data read is valid. There are three methods by which to check whether the data being read is valid.

- Checking the I2C_TXE# line, which indicates whether the transmit buffer is empty. This signal can be mapped to the CBUS pins. This line does not indicate the number of bytes available. If the line is asserted, there are one or more bytes in the transmit buffer. Note that the Transmit buffer is the buffer which holds data which has come from the host computer and is going to be read by the external $\rm I^2C$ master.
- Do a read over I²C (Master receiver, Slave transmitter) and check whether the FT-X acknowledges the address phase. The FT-X will NAK the address phase if there is no data to read.
- If bursting data, then there is not an address phase for each byte. In this case, it is not possible to tell when the buffer has emptied and therefore when you are no longer reading valid bytes. In this case, a Data Available check can be carried out first. If the byte after the general call address is 0x0C (0000 1100), the FT-X returns the Data Available Count to indicate the number of bytes available for burst read. Please also refer to section 9.3. Note that because this returns a single byte, the maximum value is 0xFF, and so a value of 0xFF indicates that there are 255 or more bytes available.

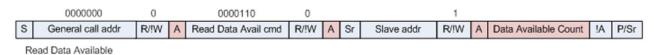


Figure 9.3: Checking the Data Available Count

Flow Control when Writing

When writing data (data going from I^2C toward the host computer), it is important to check if there is space available and if the FT-X accepted the byte written. There are two methods by which to check whether space is available.

- Check the I2C_RXF# line, which indicates whether the Receive buffer is full. This line indicates that there is at least one empty byte available in the buffer. However, there is no indication of

Version 1.3

Document No.: FT_000628 Clearance No.: FTDI# 265

how many bytes are available. This signal can be mapped to the CBUS pins. Note that the Receive buffer is the buffer which holds data which has come from the external I^2C master and is going to the host computer over USB.

- Do a write over I²C (Master transmitter, Slave receiver) and check if the FT-X ACKs. The FT-X will NAK if there is no space in the buffer for the data to be written into. The FT-X will NACK in the address phase if this is the first byte being written and there is no space available. If the buffer becomes full during a burst write, the FT-X will NACK any bytes during the data phase which cannot be accommodated in the buffer.

Note that because the acknowledgement can be checked for each byte written (since the FT-X slave is generating the acknowledge when writing to it), there is no command to ask the FT-X how much buffer space is available.

9.3 Other I²C Commands

Soft reset

This uses the General Call Address. If the second byte is 0x06 (0000 0110) it will be interpreted by the FT-X as the Soft Reset command. This will reset the chip and clear all buffers.

Flush command

This uses the General Call Address. If the second byte is 0x0E ($0000\ 1110$) it will be interpreted by the FT-X as the Flush command and the Transmit and Receive buffers will be flushed of all data.

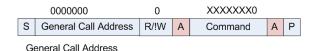


Figure 9.4: Flush data command

Read Data Available command

This uses the General Call Address. If the second byte is 0x0C (0000 1100) it will be interpreted by the block as the Read Data Available command and on the next I^2C read cycle following this command, the data will hold the number of bytes available for burst read.

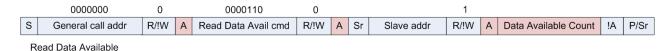


Figure 9.5: Reading the amount of data available

USB State command

This uses the General Call Address. If the second byte is 0x16 (0001 0110) it will be interpreted by the block as the USB State command and on the next read cycle following this command, the data will hold the coded USB State value. The USB state allows you to check the current USB enumeration state:

0x00 = Suspended.

0x01 = Default.

0x02 = Addressed.

0x03 = Configured.

Note: The Configured state is the normal operating state.



Version 1.3

Document No.: FT_000628 Clearance No.: FTDI# 265

Further details of these states can be found in Chapter 9 of the USB 2.0 Specification from the USB Implementers Forum website (http://www.usb.org).

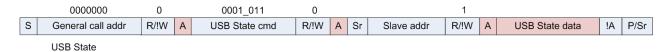


Figure 9.6: Checking the USB State

Device ID command

This command uses the Slave address of the FT-X. The master issues the 1111 100 0 command (0x7c write) followed by the slave address with the direction bit as either 0 or 1 (don't care). The master then sends a repeated start followed by the 1111 100 1 command (0x7c read). The FT-X responds with 3 bytes containing the manufacturer ID (12 bits), part ID (9 bits) and revision (3 bits). The master ends reading with a NACK.

Note: In the case where the master keeps ACKing the data, it has to wrap around and the slave (the FT-X) will keep sending the 3 bytes of its ID.



Figure 9.7: Reading the Device ID

Version 1.3

Document No.: FT_000628 Clearance No.: FTDI# 265

10 Internal MTP Memory Configuration

The FT200XD includes an internal MTP memory which holds the USB configuration descriptors, other configuration data for the chip and also user data areas. Following a power-on reset or a USB reset the FT200XD will scan its internal MTP memory and read the USB configuration descriptors stored there

In many cases, the default values programmed into the MTP memory will be suitable and no reprogramming will be necessary. The defaults can be found in Section 10.1.

The MTP memory in the FT200XD can be programmed over USB or over the I^2C bus if the values need to be changed for a particular application. Further details of this are provided from section 10.2 onwards.

Users who do not have their own USB Vendor ID but who would like to use a unique Product ID in their design can apply to FTDI for a free block of unique PIDs. See TN_100 – USB Vendor ID/Product ID Guidelines for more details.

10.1 Default Values

The default factory programmed values of the internal MTP memory are shown in the following table:

Parameter	Value	Notes
USB Vendor ID (VID)	0403h	FTDI default VID (hex)
USB Product UD (PID)	6015h	FTDI default PID (hex)
Serial Number Enabled	Yes	
Serial Number	See Note	A unique serial number is generated and programmed into the MTP memory during device final test.
Pull down I/O Pins in USB Suspend	Disabled	Enabling this option will make the device pull down on the I ² C and CBUS0 pins when in USB suspend mode (PWREN# is high).
Manufacturer Name	FTDI	
Product Description	FT200XD USB I2C	
Max Bus Power Current	90mA	
Power Source	Bus Powered	
Device Type	FT200XD	
		Returns USB 2.0 device description to the host.
USB Version	0200	Note: The device is a USB 2.0 Full Speed device (12Mb/s) as opposed to a USB 2.0 Hi-Speed device (480Mb/s).
Remote Wake Up	Disabled	
DBUS Drive Current Strength	4mA	Options are 4mA, 8mA, 12mA, 16mA
DBUS slew rate	Slow	Options are slow or fast
DBUS Schmitt Trigger	Normal	Options are normal or Schmitt



Version 1.3

Document No.: FT 000628 Clearance No.: FTDI# 265

Enable		
CBUS Drive Current Strength	4mA	Options are 4mA, 8mA, 12mA, 16mA
CBUS slew rate	Slow	Options are slow or fast
CBUS Schmitt Trigger Enable	Normal	Options are normal or Schmitt
Load VCP Driver	Disabled	Enabling this will load the VCP driver interface for the device.
I ² C Address	22h	The I ² C device address
I ² C Device ID		The I ² C device ID
CBUS0	Keep_Awake#	Prevents the device from entering suspend state when unplugged. May be used if programming the MTP memory over I ² C

Table 10.1 Default Internal MTP memory Configuration

10.2 Methods of Programming the MTP Memory

10.2.1 Programming the MTP memory over USB

The MTP memory on all FT-X devices can be programmed over USB. This method is the same as for the EEPROM on other FTDI devices such as the FT232R. No additional hardware, connections or programming voltages are required. The device is simply connected to the host computer in the same way that it would be for normal applications, and the FT_Prog utility is used to set the required options and program the device.

The FT_Prog utility is provided free-of-charge from the FTDI website, and can be found at the link below. The user guide is also available at this link.

http://www.ftdichip.com/Support/Utilities.htm#FT Prog

Additionally, D2XX commands can be used to program the MTP memory from within user applications. For more information on the commands available, please see the D2XX Programmers Guide below.

 $\underline{\text{http://www.ftdichip.com/Support/Documents/ProgramGuides/D2XX}} \ \ \underline{\text{Programmer's Guide(FT 000071).p}} \ \underline{\text{df}}$

10.2.2 Programming the MTP memory over I²C

In the FT200XD device, it is possible to program the MTP memory over its I^2C interface. This is the same interface which is used in the normal application of the FT200XD and would normally be connected to the I^2C master implemented in a microcontroller (MCU) or FPGA. However, special commands can also be used to access the MTP memory in the FT200XD over the same I^2C connection, allowing the MCU/FPGA to read and write locations in the MTP memory. No additional hardware, connections or programming voltages are required.

Two examples where it may be desired to use the I^2C interface to write and read the MTP Memory are given below. In some cases, the application may use both of these possibilities.

- 1. To store and retrieve application specific data such as calibration constants in the user area (e.g. if the overall application was an analog measurement system). This can avoid the need for an extra EEPROM chip on the application board.
- 2. To read and write the configuration data (e.g. custom VID, PID, description strings or CBUS signal selection to enable signals for battery charging etc) without a USB host. This could allow an MCU/FPGA to configure the FT200XD during production testing of the finished device or even when in use in the field.

Version 1.3

Document No.: FT_000628 Clearance No.: FTDI# 265

The information in the rest of this chapter can be used to implement the storing and reading of application data in the user area as in example 1 above. Example 2 requires details of the configuration data stored in the MTP memory. Further details can be found in the following application note:

http://www.ftdichip.com/Support/Documents/AppNotes/AN 201 FT-X%20MTP%20Memory%20Configuration.pdf

10.3 Memory Map

The FT-X family MTP memory has various areas which come under three main categories:

- User Memory Area
- Configuration Memory Area (writable)
- Configuration Memory Area (non-writable)

Memory Area Description	Word Address
User Memory Area 2 Accessible via USB, I ² C and FT1248	0x3FF - 0x80
Configuration Memory Area Accessible via USB, I ² C and FT1248	0x7E - 0x50
Configuration Memory Area Cannot be written	0x4E - 0x40
User Memory Area 1 Accessible via USB, I ² C and FT1248	0x3E - 0x12
Configuration Memory Area Accessible via USB, I ² C and FT1248	0x10 - 0x00

Figure 10.1 Simplified memory map for the FT-X

User Memory Area

The User Memory Areas are highlighted in Green on the memory map. They can be read and written via both USB and I^2C . All locations within this range are freely programmable; no areas have special functions and there is no checksum for the user area.

Note that the application should take into account the specification for the number of write cycles in Section 6.4 if it will be writing to the MTP memory multiple times.

Configuration Memory Area (writable)

This area stores the configuration data for the device, including the data which is returned to the host in the configuration descriptors (e.g. the VID, PID and string descriptions) and also values which set the hardware configuration (the signal assigned to each CBUS pin for example).



Version 1.3

Document No.: FT_000628 Clearance No.: FTDI# 265

These values can have a significant effect on the behaviour of the device. Steps must be taken to ensure that these locations are not written to un-intentionally by an application which is intended to access only the user area.

This area is included in a checksum which covers configuration areas of the memory, and so changing any value can also cause this checksum to fail.

Configuration Memory Area (non-writable)

This is a reserved area and the application should not write to this area of memory. Any attempt to write these locations will fail.

10.4 Hardware Requirements

The hardware is the same as for a typical USB- I^2C application and no additional hardware or programming voltages are required. The I^2C connections are the same as shown in Section 8.1. For the USB connections, either a bus-powered configuration (see Section 7.1 and 7.3) or a self-powered configuration (see Section 7.2) could be used.

10.5 Protocol

The I²C MTP memory protocol consists of 3 commands:

- Address MTP memory (0x10)
- Write MTP memory (0x12)
- Read MTP memory (0x14)

For further details on the I^2C protocol, refer to section 5.

10.5.1 Address MTP memory (0x10)

This consists of a general call with a command phase followed by 2 data bytes which represent the MTP memory address allowing users to address, potentially, up to 64K byte addresses.

10.5.2 Write MTP memory (0x12)

This consists of a general call with a command phase followed by 1 data byte which shall be programmed into the MTP memory at the address location set by the MTP memory address command.

10.5.3 Read MTP memory (0x14)

This consists of a general call with a command phase followed by 1 data byte which is the data read from the MTP memory at the address location set by the MTP memory address command.

10.5.4 Examples of Writing and Reading

When performing MTP memory write and read requests via the I^2C protocol, users must first issue the MTP address command along with 2 bytes representing the MTP memory address. The acknowledge phase of this command represents the current status of the MTP memory (whether it is busy or not). If the MTP memory is being accessed during an I^2C access then the respective command and data phases will NAK the master. The address will only be updated when the MTP memory is inactive.

Writing

The first part of the communication sets the address, and this is followed by the write command along with the data to be written. The MTP memory write itself will be initiated when the FT200XD receives an MTP memory write command followed by a single data byte. The ACK phase represents the current activity of the MTP memory (whether it is busy or not busy). A successful write will only occur when both status phases acknowledge the master indicating that the MTP memory can start the write. Users wishing



Version 1.3

Document No.: FT_000628 Clearance No.: FTDI# 265

to determine if the MTP memory write was successful should immediately try an MTP memory read to verify the new contents.

This process of writing to the MTP memory is shown below:

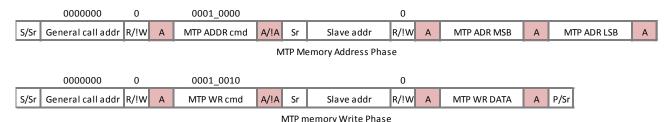


Figure 10.2 Write EEPROM command sequence

Reading

In a similar way, the read is carried out as shown below. The first part of the communication sets the address, and this is followed by the read command and a read cycle used to retrieve the data read back from that address.

An MTP memory read will be initiated when the I^2C slave receives an MTP read command. The acknowledge during the command phase indicates whether or not the MTP memory will be able to service the read request. If it is possible to carry out the read, the I^2C moves into the data phase where it can either continue with the read transaction until the slave successful returns an ACK along with the data or if it receives NAK during the data phase it can abort the read transfer and try again.

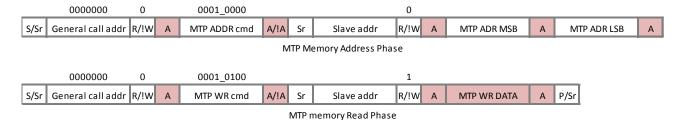


Figure 10.3 Read EEPROM command sequence

Version 1.3
Document No.: FT 000628 Clearance No.: FTDI# 265

11 Package Parameters

The FT200XD is available in a 10 pin DFN package, the FT200XD. The solder reflow profile for the package is described in Section 0.

11.1 DFN-10 Package Mechanical Dimensions

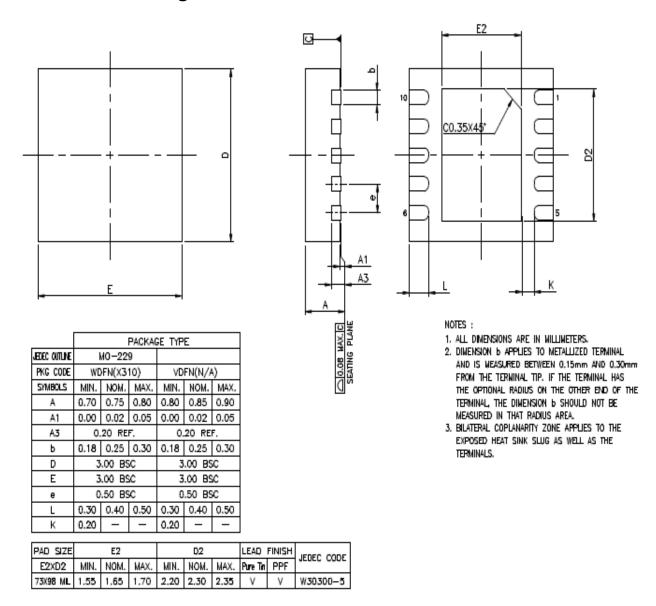


Figure 11.1 DFN-10 Package Dimensions

The FT200XD is supplied in a RoHS compliant leadless DFN-10package. The package is lead (Pb) free, and uses a 'green' compound. The package is fully compliant with European Union directive 2002/95/EC.

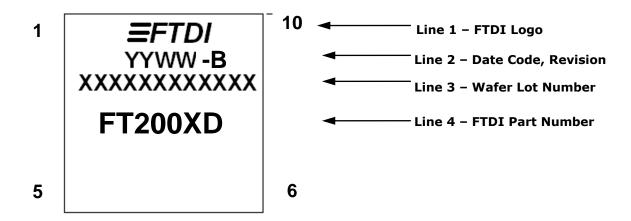
This package is nominally $3.00 \, \text{mm} \times 3.00 \, \text{mm}$. The solder pads are on a $0.50 \, \text{mm}$ pitch. The above mechanical drawing shows the DFN-10 package. All dimensions are in millimetres.

The centre pad on the base of the FT200XD is internally connected to GND. Do not place tracks on the top layer of the PCB in this area.

Version 1.3



11.2 Package Markings



The date code format is YYXWW where XWW = 2 digit week number, YY = 2 digit year number. The code **XXXXXXX** is the manufacturing LOT code.



11.3 Solder Reflow Profile

The FT200XD is supplied in Pb free DFN-10 packages. The recommended solder reflow profile for the package is shown in Figure 11.2.

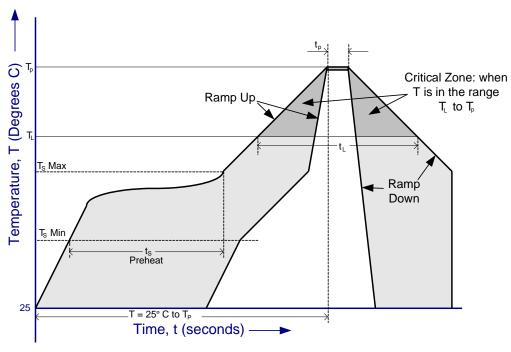


Figure 11.2 FT200XD Solder Reflow Profile

The recommended values for the solder reflow profile are detailed in Table 11.1. Values are shown for both a completely Pb free solder process (i.e. the FT200XD is used with Pb free solder), and for a non-Pb free solder process (i.e. the FT200XD is used with non-Pb free solder).

Profile Feature	Pb Free Solder Process	Non-Pb Free Solder Process
Average Ramp Up Rate $(T_s$ to $T_p)$	3°C / second Max.	3°C / Second Max.
Preheat - Temperature Min (T _s Min.) - Temperature Max (T _s Max.) - Time (t _s Min to t _s Max)	150°C 200°C 60 to 120 seconds	100°C 150°C 60 to 120 seconds
Time Maintained Above Critical Temperature $T_L\colon$ - Temperature (T_L) - Time (t_L)	217°C 60 to 150 seconds	183°C 60 to 150 seconds
Peak Temperature (T _p)	260°C	240°C
Time within 5°C of actual Peak Temperature (t_p)	20 to 40 seconds	20 to 40 seconds
Ramp Down Rate	6°C / second Max.	6°C / second Max.
Time for T= 25°C to Peak Temperature, T _p	8 minutes Max.	6 minutes Max.

Table 11.1 Reflow Profile Parameter Values



Version 1.3

Document No.: FT 000628 Clearance No.: FTDI# 265

12 Contact Information

Head Office - Glasgow, UK

Future Technology Devices International Limited Unit 1, 2 Seaward Place, Centurion Business Park Glasgow G41 1HH

United Kingdom

Tel: +44 (0) 141 429 2777 Fax: +44 (0) 141 429 2758

E-mail (Sales) sales1@ftdichip.com
E-mail (Support) support1@ftdichip.com
E-mail (General Enquiries) admin1@ftdichip.com

Branch Office - Taipei, Taiwan

Future Technology Devices International Limited (Taiwan)

2F, No. 516, Sec. 1, NeiHu Road

Taipei 114 Taiwan , R.O.C.

Tel: +886 (0) 2 8791 3570 Fax: +886 (0) 2 8791 3576

Branch Office - Hillsboro, Oregon, USA

Future Technology Devices International Limited

(USA)

7130 SW Fir Loop Tigard, OR 97223

USA

Tel: +1 (503) 547 0988 Fax: +1 (503) 547 0987

E-Mail (Sales)

E-Mail (Support)

E-Mail (General Enquiries)

us.sales@ftdichip.com

us.support@ftdichip.com

us.admin@ftdichip.com

Branch Office - Shanghai, China

Future Technology Devices International Limited

(China)

Room 408, 317 Xianxia Road,

Shanghai, 200051

China

Tel: +86 21 62351596 Fax: +86 21 62351595

Web Site

http://ftdichip.com

System and equipment manufacturers and designers are responsible to ensure that their systems, and any Future Technology Devices International Ltd (FTDI) devices incorporated in their systems, meet all applicable safety, regulatory and system-level performance requirements. All application-related information in this document (including application descriptions, suggested FTDI devices and other materials) is provided for reference only. While FTDI has taken care to assure it is accurate, this information is subject to customer confirmation, and FTDI disclaims all liability for system designs and for any applications assistance provided by FTDI. Use of FTDI devices in life support and/or safety applications is entirely at the user's risk, and the user agrees to defend, indemnify and hold harmless FTDI from any and all damages, claims, suits or expense resulting from such use. This document is subject to change without notice. No freedom to use patents or other intellectual property rights is implied by the publication of this document. Neither the whole nor any part of the information contained in, or the product described in this document, may be adapted or reproduced in any material or electronic form without the prior written consent of the copyright holder. Future Technology Devices International Ltd, Unit 1, 2 Seaward Place, Centurion Business Park, Glasgow G41 1HH, United Kingdom. Scotland Registered Company Number: SC136640



Version 1.3

Document No.: FT_000628 Clearance No.: FTDI# 265

Appendix A - References

Useful Application Notes

http://www.ftdichip.com/Documents/AppNotes/AN232R-01 FT232R BitBangModes.pdf

http://www.ftdichip.com/Documents/AppNotes/AN 107 AdvancedDriverOptions AN 000073.pdf

http://www.ftdichip.com/Documents/AppNotes/AN 121 FTDI Device EEPROM User Area Usage.pdf

http://www.ftdichip.com/Documents/InstallGuides.htm

http://www.ftdichip.com/Support/Documents/TechnicalNotes/TN 100 USB VID-PID Guidelines.pdf

http://www.ftdichip.com/Support/Documents/AppNotes/AN 175 Battery%20Charging%20Over%20USB %20with%20FTEX%20Devices.pdf

http://i2c2p.twibright.com/spec/i2c.pdf

http://www.usb.org/developers/devclass_docs/BCv1.2_011912.zip

Version 1.3

Document No.: FT_000628 Clearance No.: FTDI# 265

Appendix B - List of Figures and Tables

List of Figures
Figure 2.1FT200XD Block Diagram4
Figure 3.1 DFN Schematic Symbol7
Figure 7.1 Bus Powered Configuration
Figure 7.2 Self Powered Configuration20
Figure 7.3 Bus Powered with Power Switching Configuration21
Figure 8.1 Application Example showing USB to I ² C Converter22
Figure 8.2 USB Battery Charging Detection
Figure 9.2: Data transfers with 7-bit and 10-bit addressing modes
Figure 9.3: Checking the Data Available Count28
Figure 9.4: Flush data command29
Figure 9.5: Reading the amount of data available29
Figure 9.6: Checking the USB State30
Figure 9.7: Reading the Device ID30
Figure 10.1 Simplified memory map for the FT-X33
Figure 10.2 Write EEPROM command sequence35
Figure 10.3 Read EEPROM command sequence35
Figure 11.1 DFN-10 Package Dimensions36
Figure 11.2 FT200XD Solder Reflow Profile
List of Tables
Table 1.1 Ordering part numbers2
Table 3.1 Power and Ground
Table 3.2 Common Function pins
Table 3.3 I ² C Interface and CBUS Group (see note 1)
Table 3.4 CBUS Configuration Control9
Table 6.1 Absolute Maximum Ratings
Table 6.2 ESD and Latch-Up Specifications
Table 6.3 Operating Voltage and Current
Table 6.4 I/O Pin Characteristics VCCIO = +3.3V (except USB PHY pins)
Table 6.5 I/O Pin Characteristics VCCIO = +2.5V (except USB PHY pins)
Table 6.6 I/O Pin Characteristics VCCIO = +1.8V (except USB PHY pins)
Table 6.7 USB I/O Pin (USBDP, USBDM) Characteristics
Table 6.8 MTP Memory Characteristics
Table 6.9 Internal Clock Characteristics
Table 10.1 Default Internal MTP memory Configuration32



Version 1.3

Document No.: FT_000628 Clearance No.: FTDI# 265

Appendix C - Revision History

Document Title: USB I2C SLAVE IC FT200XD

Document Reference No.: FT_000628
Clearance No.: FTDI# 265

Product Page: http://www.ftdichip.com/Products/ICs/FTEX.htm

Document Feedback: Send Feedback

Version 1.0 Initial Release 8th February 2012

Version 1.1 Added USB compliance in section 1.3 17th April 2012

Clarified MTP reliability in table 6.8
Edited Table 9.1: Added I2C address
and changed Load VCP Driver to Disabled

Version 1.2 Added section 9 with details of USB and I2C Interfacing 15th August 2012

Added link to AN_201 (MTP Memory Configuration) in

section 10

Removed references to LED signals on the CBUS pins as these are only available on the UART members of the FT-X

family.

Removed section 8.3 showing connection of the Tx/Rx LEDs.

Version 1.3 Added 5V tolerant statement on front page

Updated TID info

Updated US address Feb 2013



Мы молодая и активно развивающаяся компания в области поставок электронных компонентов. Мы поставляем электронные компоненты отечественного и импортного производства напрямую от производителей и с крупнейших складов мира.

Благодаря сотрудничеству с мировыми поставщиками мы осуществляем комплексные и плановые поставки широчайшего спектра электронных компонентов.

Собственная эффективная логистика и склад в обеспечивает надежную поставку продукции в точно указанные сроки по всей России.

Мы осуществляем техническую поддержку нашим клиентам и предпродажную проверку качества продукции. На все поставляемые продукты мы предоставляем гарантию.

Осуществляем поставки продукции под контролем ВП МО РФ на предприятия военно-промышленного комплекса России, а также работаем в рамках 275 ФЗ с открытием отдельных счетов в уполномоченном банке. Система менеджмента качества компании соответствует требованиям ГОСТ ISO 9001.

Минимальные сроки поставки, гибкие цены, неограниченный ассортимент и индивидуальный подход к клиентам являются основой для выстраивания долгосрочного и эффективного сотрудничества с предприятиями радиоэлектронной промышленности, предприятиями ВПК и научноисследовательскими институтами России.

С нами вы становитесь еще успешнее!

Наши контакты:

Телефон: +7 812 627 14 35

Электронная почта: sales@st-electron.ru

Адрес: 198099, Санкт-Петербург,

Промышленная ул, дом № 19, литера Н,

помещение 100-Н Офис 331